NSN 5962-01-343-3153

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View Online at https://aerobasegroup.com/nsn/5962-01-343-3153

Overall Length:

Between 0.890 inches and 0.930 inches

Overall Height:

Between 0.230 inches and 0.350 inches

Overall Width:

Between 0.290 inches and 0.320 inches

Body Length:

Between 0.890 inches and 0.930 inches

Body Width:

Between 0.280 inches and 0.310 inches

Body Height:

Between 0.080 inches and 0.120 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-60.0/+160.0 degrees celsius

Features Provided:

W/enable and w/disable and high impedance

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

16 input

Current Rating Per Characteristic:

160.00 milliamperes forward current, nonrepetitive, peak total value absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Capitance Rating Per Characteristic:

10.00 input picofarads and 15.00 output picofarads

Memory Device Type:

Prom

Terminal Type And Quantity:

18 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

